

Very low offset single bipolar operational amplifier

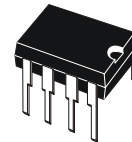
Features

- Extremely low offset: 150 μ V/ max.
- Low input bias current: 1.8nA
- LOW V_{io} drift: 0.5 μ V/ $^{\circ}$ C
- Ultra stable with time: 2 μ V/month max.
- Wide supply voltage range: \pm 3V to \pm 22V
- Temperature range: 0 $^{\circ}$ C to -105 $^{\circ}$ C

Description

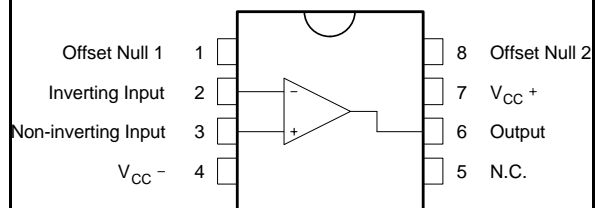
The OP07 is a very high precision op-amp with an offset voltage maximum of 150 μ V.

Offering also low input current (1.8nA) and high gain (400V/mV), the OP07C is particularly suitable for instrumentation applications.



**N
DIP8**
(Plastic package)

Pin connections
(top view)



1 Schematic diagram

Figure 1. Schematic diagram

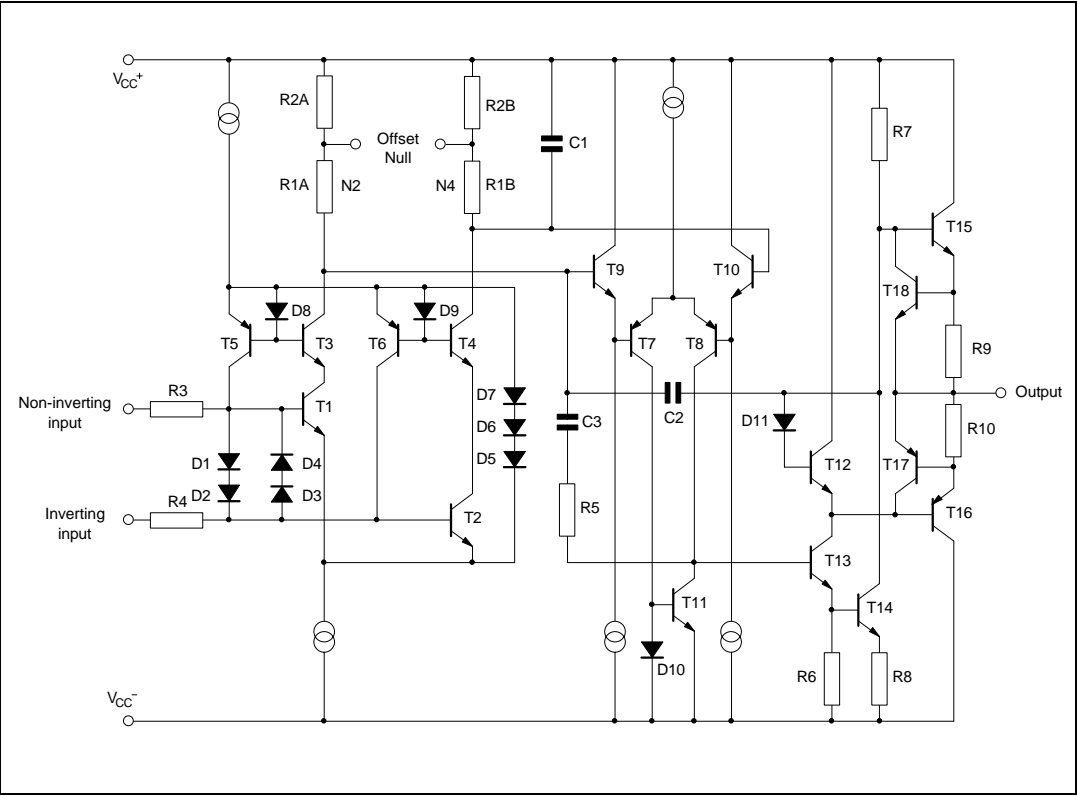
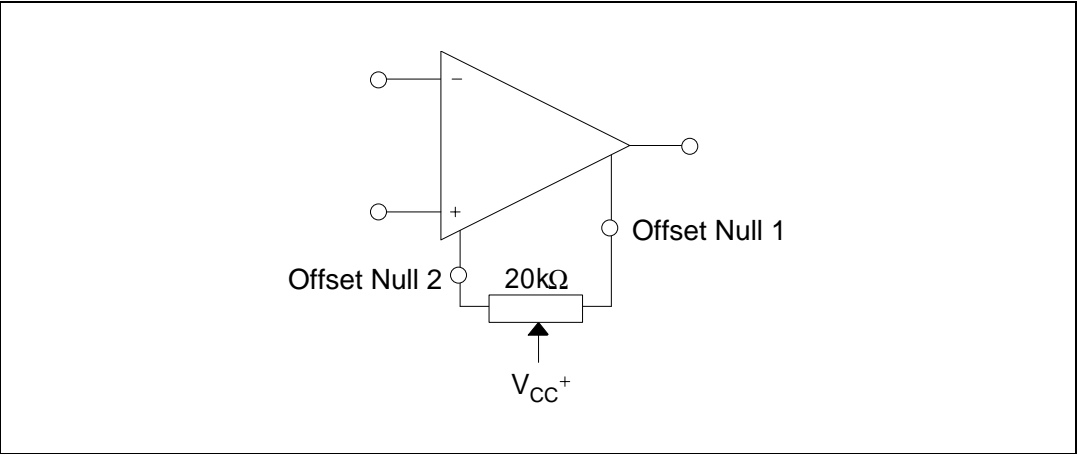


Figure 2. Input offset voltage nulling circuit



2 Absolute maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage	± 22	V
V_{id}	Differential input voltage	± 30	V
V_i	Input voltage	± 22	V
T_{oper}	Operating temperature	-40 to 105	°C
T_{stg}	Storage temperature	-65 to 150	°C
R_{thja}	Thermal resistance junction to ambient ^{(1) (2)} DIP8	85	°C/W
R_{thjc}	Thermal resistance junction to case ^{(1) (2)} DIP8	41	°C/W
ESD	HBM: human body model ⁽³⁾	1.5	kV
	MM: machine model ⁽⁴⁾	200	V
	CDM: charged device model ⁽⁵⁾	1.5	kV

1. Short-circuits can cause excessive heating and destructive dissipation.
2. R_{th} are typical values.
3. Human body model: 100pF discharged through a 1.5k Ω resistor between two pins of the device, done for all couples of pin combinations with other pins floating.
4. Machine model: a 200pF cap is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). Done for all couples of pin combinations with other pins floating.
5. Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to the ground.

3 Electrical characteristics

Table 2. $V_{CC^+} = 15\text{ V}$, $V_{CC^-} = \text{Ground}$, $T_{\text{amb}} = 25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input offset voltage $0^\circ\text{C} \leq T_{\text{amb}} \leq +105^\circ\text{C}$		60	150 250	μV
	Long term input offset - voltage stability ⁽¹⁾		0.4	2	$\mu\text{V/Mo}$
DV_{io}	Input offset voltage drift		0.5	1.8	$\mu\text{V}/^\circ\text{C}$
I_{io}	Input offset current ($V_{ic} = 0\text{V}$) $0^\circ\text{C} \leq T_{\text{amb}} \leq +105^\circ\text{C}$		0.8	6 7	nA
DI_{io}	Input offset current drift		15	50	$\text{pA}/^\circ\text{C}$
DI_{ib}	Input bias current drift		15	50	$\text{pA}/^\circ\text{C}$
R_o	Open loop output resistance		60		Ω
R_{id}	Differential input resistance		33		MW
R_{ic}	Common mode input resistance		120		GW
V_{icm}	Input common mode voltage range $0^\circ\text{C} \leq T_{\text{amb}} \leq +105^\circ\text{C}$	± 13 ± 13	± 13.5		V
CMR	Common-mode rejection ratio ($V_{ic} = V_{icm\text{-min}}$) $0^\circ\text{C} \leq T_{\text{amb}} \leq +105^\circ\text{C}$	100 97	120		dB
SVR	Supply voltage rejection ratio ($V_{CC} = \pm 3$ to $\pm 18\text{V}$) $0^\circ\text{C} \leq T_{\text{amb}} \leq +105^\circ\text{C}$	90 86	104		dB
A_{vd}	Large signal voltage gain $V_{CC} = \pm 15$, $R_L = 2\text{k}\Omega$, $V_O = \pm 10\text{V}$ $0^\circ\text{C} \leq T_{\text{amb}} \leq +105^\circ\text{C}$ $V_{CC} = \pm 3$, $R_L = 500\Omega$, $V_O = \pm 0.5\text{V}$	120 100 100	400 400		V/mV
V_{opp}	Output voltage swing $R_L = 10\text{k}\Omega$ $R_L = 2\text{k}\Omega$ $R_L = 1\text{k}\Omega$ $0^\circ\text{C} \leq T_{\text{amb}} \leq +105^\circ\text{C}$ $R_L = 2\text{k}\Omega$	± 12 ± 11.5 ± 11	± 13 ± 12.8 ± 12		V
SR	Slew rate ($R_L = 2\text{k}\Omega$, $C_L = 100\text{pF}$)		0.17		V/ μs
GBP	Gain bandwidth product ($R_L = 2\text{k}\Omega$, $C_L = 100\text{pF}$, $f = 100\text{kHz}$)		0.5		MHz
I_{CC}	Supply current - no load $0^\circ\text{C} \leq T_{\text{amb}} \leq +105^\circ\text{C}$ $V_{CC} = \pm 3\text{V}$		2.7 0.67	5 6 1.3	mA

Table 2. $V_{CC^+} = 15\text{ V}$, $V_{CC^-} = \text{Ground}$, $T_{\text{amb}} = 25^\circ\text{ C}$ (unless otherwise specified) (continued)

Symbol	Parameter	Min.	Typ.	Max.	Unit
e_n	Equivalent input noise voltage f = 10Hz f = 100Hz f = 1kHz		11 10.5 10	20 13.5 11.5	$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
i_n	Equivalent input noise current f = 10Hz f = 100Hz f = 1kHz		0.3 0.2 0.1	0.9 0.3 0.2	$\frac{\text{pA}}{\sqrt{\text{Hz}}}$

1. Long term input offset voltage stability refers to the average trend line of V_{io} vs time over extended periods after the first 30 days of operation.

4 Package information

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Figure 3. DIP8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			5.33			0.210
A1	0.38			0.015		
A2	2.92	3.30	4.95	0.115	0.130	0.195
b	0.36	0.46	0.56	0.014	0.018	0.022
b2	1.14	1.52	1.78	0.045	0.060	0.070
c	0.20	0.25	0.36	0.008	0.010	0.014
D	9.02	9.27	10.16	0.355	0.365	0.400
E	7.62	7.87	8.26	0.300	0.310	0.325
E1	6.10	6.35	7.11	0.240	0.250	0.280
e		2.54			0.100	
eA		7.62			0.300	
eB			10.92			0.430
L	2.92	3.30	3.81	0.115	0.130	0.150

The figure includes four mechanical drawings of the DIP8 package:

- Side View (Top Left):** Shows the package profile with dimensions A (total height), A1 (lead height), A2 (body height), b (lead thickness), b2 (lead width), and e (lead pitch).
- Front View (Top Right):** Shows the package width with dimensions E (body width), c (lead thickness), eA (lead pitch), and eB (total width).
- Top View (Bottom Left):** Shows the package footprint with dimensions D (body length), E1 (lead pitch), and pin numbers 1, 4, 5, 8.
- Cross-section (Bottom Right):** Shows the lead profile with dimension H (lead thickness) and a note 'GAUGE PLANE 0.38' indicating the measurement point for the lead thickness.

5 Ordering information

Table 3. Order codes

Part number	Temperature range	Package	Packing	Marking
OP07C OP07CN	0°C, +105°C	DIP8	Tube	OP07CN

6 Revision history

Table 4. Document revision history

Date	Revision	Changes
20-May-2003	1	Initial release.
23-Jul-2007	2	Format update. R_{thja} , R_{thjc} , and ESD values added in Table 1: Absolute maximum ratings . Temperature range modified to 0-105°C.

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